

## 6 A Snubberless™ Triac

#### **Features**

- I<sub>T(RMS)</sub> = 6 A
- $\blacksquare$  V<sub>DRM</sub> = V<sub>RRM</sub> = 600 and 800 V

#### **Description**

The high commutation performance of this device is based on Snubberless technology from ST. The T630W is especially suited for high inductance loads. This device complies with UL standards (Ref. E81734).

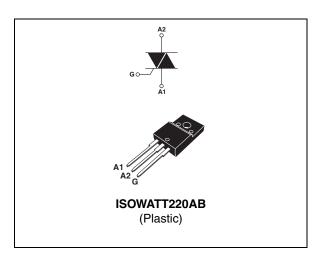


Table 1. Device summary

Symbol	Value	Unit
I <sub>T(RMS)</sub>	6	Α
$V_{DRM}/V_{RRM}$	600 and 800	V
I <sub>GT</sub>	30	mA

Characteristics T630W

## 1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit
I <sub>T(RMS)</sub>	On-state rms current (full sine wave)		T <sub>c</sub> = 105°C	6	Α
1.	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	80	Α
TSM	TSM   (6.11 T ::4:-1 0500)	F = 60 Hz	t = 16.7 ms	84	Α
l <sup>2</sup> t	I <sup>2</sup> t Value for fusing	t <sub>p</sub> = 10 ms		36	A <sup>2</sup> s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	F = 120 Hz		50	A/μs
I <sub>GM</sub>	Peak gate current	$t_p = 20 \ \mu s$ $T_j = 125^{\circ} C$		4	Α
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 125^{\circ}C$		1	W	
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range		- 40 to + 150 - 40 to + 125	°C	

Table 3. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Test conditions		Quadrant		Value	Unit
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 \text{ V}  R_L = 30 \Omega$		I - II - III	Max.	30	mA
V <sub>GT</sub>			1 - 11 - 111	Max.	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$	T <sub>j</sub> = 125 °C	1 - 11 - 111	Min.	0.2	V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 100 mA			Max.	50	mA
	I <sub>L</sub>		I - III	Max.	70	mA
'L			II	IVIAX.	80	IIIA
dV/dt (2)	$V_D = 67 \% V_{DRM}$ gate open $T_j = 125 \degree C$			Min.	500	V/µs
(dl/dt)c (2)	Without snubber $T_j = 125$ °C			Min.	4.5	A/ms

<sup>1.</sup> Minimum  $I_{\mbox{\scriptsize GT}}$  is guaranted at 5% of  $I_{\mbox{\scriptsize GT}}$  max.

Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
V <sub>T</sub> <sup>(1)</sup>	$I_{TM} = 8.5 \text{ A}$ $t_p = 380  \mu\text{s}$	T <sub>j</sub> = 25 °C	Max.	1.4	V
V <sub>t0</sub> <sup>(1)</sup>	Threshold voltage	T <sub>j</sub> = 125 °C	Max.	0.85	V
R <sub>d</sub> <sup>(1)</sup>	Dynamic resistance	T <sub>j</sub> = 125 °C	Max.	50	mΩ
I <sub>DRM</sub>	V -V	T <sub>j</sub> = 25 °C	Max.	5	μΑ
I <sub>RRM</sub>	$V_{DRM} = V_{RRM}$	T <sub>j</sub> = 125 °C	iviax.	1	mA

<sup>1.</sup> For both polarities of A2 referenced to A1

<sup>2.</sup> For both polarities of A2 referenced to A1

T630W Characteristics

Table 5. Thermal resistance

Symbol	Parameter		Unit
R <sub>th(j-c)</sub>	Junction to case (AC) (360° conduction angle)	3.4	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	50	°C/W

Figure 1. Maximum power dissipation versus Figure 2. On-state rms current versus case rms on-state current temperature

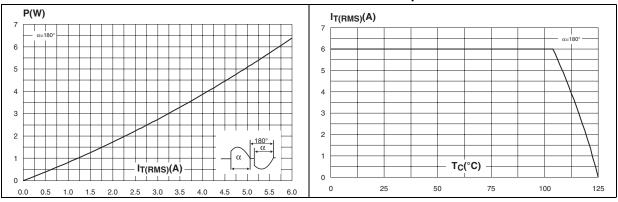


Figure 4.

Figure 3. Relative variation of thermal impedance versus pulse duration

ITM(A)

100

T, max.

T, max.

T, = T, max.

T, = T, max.

T, = 25°C

VTM(V)

1 0 1 2 3 4 5 6

**On-state characteristics** 

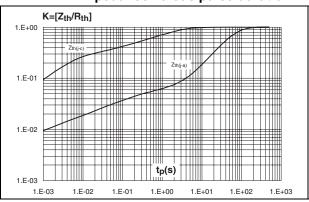
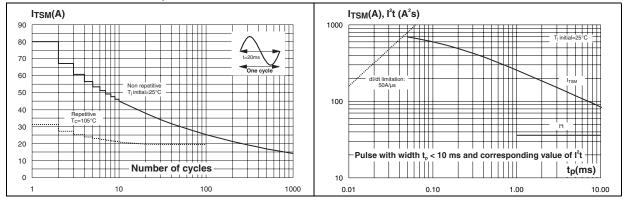


Figure 5. Surge peak on-state current versus Figure 6. Non-repetitive surge peak on-state number of cycles current for a sinusoidal



Characteristics T630W

Figure 7. Relative variation of gate trigger current, holding current and latching

Figure 8. Relative variation of critical rate of decrease of main current versus reapplied (dV/dt)c (typical value)

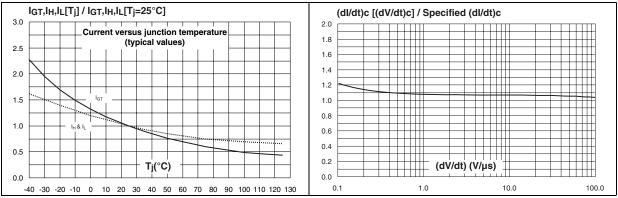
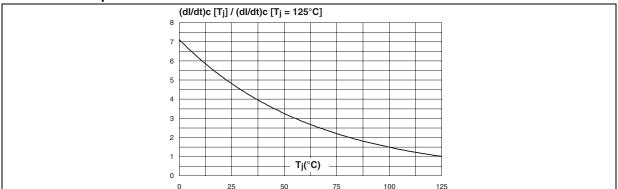
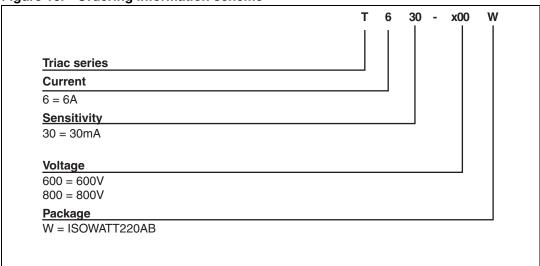


Figure 9. Relative variation of critical rate of decrease of main current versus junction temperature



# 2 Ordering information scheme

Figure 10. Ordering information scheme



Package information T630W

## 3 Package information

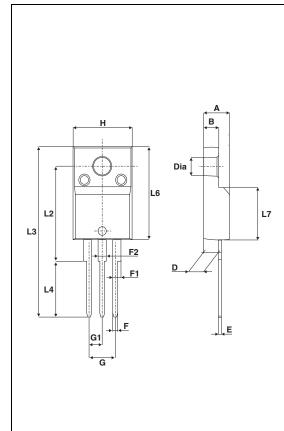
Epoxy meets UL94, V0

• Cooling method: by conduction (C)

Recommended torque: 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. ISOWATT220AB dimensions



		Dimensions			
Ref.	Millimeters		Inc	hes	
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.173	0.181	
В	2.50	2.70	0.098	0.106	
D	2.50	2.75	0.098	0.108	
Е	0.40	0.70	0.016	0.028	
F	0.75	1.00	0.030	0.039	
F1	1.15	1.70	0.045	0.067	
F2	1.15	1.70	0.045	0.067	
G	4.95	5.20	0.195	0.205	
G1	2.40	2.70	0.094	0.106	
Н	10.00	10.40	0.394	0.409	
L2	16.00 typ.		0.630	0 typ.	
L3	28.60	30.60	1.125	1.205	
L4	9.80	10.60	0.386	0.417	
L6	15.90	16.40	0.626	0.646	
L7	9.00	9.30	0.354	0.366	
Diam	3.00	3.20	0.118	0.126	

# 4 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T630-600W	T630600W	ISOWATT220AB	2.3 g	50	Tube
T630-800W	T630800W	130WAI 1220AB	2.5 g	50	Tube

# 5 Revision history

Table 8. Document revision history

Date	Revision	Changes
March-2004	2	Last release.
09-Feb-2010	3	Document split into T620W and T630W. This document provides information for the T630W.

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America



### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Triacs category:

Click to view products by STMicroelectronics manufacturer:

Other Similar products are found below:

T2035H-6G BT137-600-0Q Z0409MF0AA2 Z0109NA 2AL2 ACST1635T-8FP BCR20RM-30LA#B00 CMA60MT1600NHR NTE5611
NTE5612 NTE5613 NTE5621 NTE5623 NTE5629 NTE5638-08 NTE5688 NTE5689 NTE5690 BTA312-600CT.127 T1210T-8G-TR
T2535T-8I T2535T-8T TN4050-12WL MAC4DLM-1G BT137-600E,127 BT137X-600D BT148W-600R,115 BT258-500R,127 BTA08-800BW3G BTA140-800,127 BTA30-600CW3G BTA30-600CW3G BTB08-800BW3G BTB16-600CW3G BTB16-600CW3G
Z0410MF0AA2 Z0109MN,135 T825T-6I T1635T-6I T1220T-6I NTE5638 TYN612MRG TYN1225RG TPDV840RG ACST1235-8FP
ACS302-6T3-TR BT134-600D,127 BT134-600G,127 BT136X-600E,127 BT139X-800,127 BTA04-700SRG